



INTEGRATED SILICON SOLUTION, INC.

## Product Change Notification

**Date:** April 26th, 2012

**Change Notification No.** IS42S32200E-002

**To:** ISSI Valued Customers

**From:** ISSI (Integrated Silicon Solution, Inc.)  
1940 Zanker Road  
San Jose, CA. 95112  
USA

**Affected Product Number:** IS42S32200E

**New Product Number:** IS42S32200L

**Description of Change:** The 2Mx32 SDRAM is transitioning from its fab location at Nanya Technology in Taoyuan, Taiwan using a 0.11um process (IS42S32200E) to Powerchip in Hsinchu City, Taiwan using a 72nm process (IS42S32200L). The new parts are the same in fit, form, and function as the old parts.

**Rationale for Change:**

This transition to a new fab and similar technology is to ensure a better lead-time and long-term product availability of ISSI's 2M x 32 SDRAM.

**Schedule:**

**New Part Status:**

Mass Production

**Change Validation Test Data:**

Available Now

**Old part Last-Time-Buy Date (LTB):**

October 30th, 2012

**Date of Complete Transition (Last delivery date):**

January 30<sup>th</sup>, 2013

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